



# Photomultiplicateurs au silicium pour nEXO

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pour la collaboration nEXO

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### Silicon Photomultipliers for nEXO

Simon Viel (Carleton University)

on behalf of the nEXO Collaboration Canadian Association of Physicists Congress June 9<sup>th</sup>, 2020

### Silicon photomultipliers (SiPM) **nEX**

- 2D array of single-photon avalanche diodes (SPADs)
  - Operated in Geiger mode

     i.e. reverse bias > breakdown voltage
- Diodes typically connected in parallel: each array is read out as one channel
  - Signal proportional to number of photons detected
- Many advantages:
  - Low mass → Low radioactivity
  - Operating voltage around 50 V
  - Resistant to electromagnetic fields
  - Operation at noble liquid temperatures!



#### Hamamatsu VUV4 2x2 MPPC array



#### Search for $0\nu\beta\beta$ in <sup>136</sup>Xe









nEXO Pre-Conceptual Design Report, arXiv:1805.11142

#### nEXO proposal at SNOLAB



 5 tonnes LXe, enriched in <sup>136</sup>Xe to 90% isotopic purity

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- Pending selection by US DOE of 0vββ detector technology and host site
- SNOLAB Cryopit cavern is committed to a large-scale 0vββ detector that could be nEXO, and is the nEXO collaboration's preferred site

nEXO Pre-Conceptual Design Report, arXiv:1805.11142

- SiPMs in barrel configuration
  - Need at least 4 m<sup>2</sup> of detection area: plan to build 5 m<sup>2</sup>
- Modular design:
  - SiPMs are mounted on **Tiles**
  - Tiles are mounted on Staves
  - Staves form the full Barrel



10 mm x 10 mm SiPMs





Prototype VUV SiPM array (FBK)

LXe-compatible ASIC electronics

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Very preliminary: Stave design with 15 x 2 Tiles



Preliminary: Barrel design with 24 Staves

- SiPMs in barrel configuration
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- Modular design:
  - SiPMs are mounted on Tiles
  - Tiles are mounted on Staves
  - Staves form the full **Barrel**
- Energy resolution in nEXO relies on the combination of charge and light collection



- Energy resolution in nEXO expected to be dominated by light detection
  - To achieve 1% energy resolution overall, need 3% total efficiency for detecting scintillation photons
    - Assuming 20% geometrical acceptance, implies 15% photodetector efficiency at the LXe scintillation wavelength (175 nm)
    - Without wavelength-shifter
    - With negligible noise
- Evaluating vacuum ultraviolet (VUV) sensitive SiPM candidate technologies



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Expected energy resolution of nEXO vs. overall photon detection efficiency, for different drift electric fields

### Photon detection requirements

Parameter	Value
Total instrumented area	$\simeq 4.5~{ m m}^2$
Overall light detection efficiency	$\epsilon_o > 3~\%$
SiPM PDE (175 nm, normal incidence)	$\epsilon_{PD} > 15~\%$
Overvoltage	$> 3~{ m V}$
Dark noise rate	$< 50  \mathrm{Hz}/\mathrm{mm}^2$
Correlated avalanche rate	< 0.2

- Photon transport simulations show that the **SiPM photodetection efficiency needs to be > 15%** 
  - Caveats: Simulations need tuning, assume SiPM reflect >50% of the photons, and assume that electrodes are reflective
  - Measurements are needed to constrain simulations
- Electronics noise negligible as long as there is enough gain (overvoltage > 3 V)
- Correlated avalanche rate < 0.2 to have negligible effect on resolution
- Dark noise rate requirement comes from trigger threshold, and easily satisfied



## SiPM measurements towards nEXO with emphasis on Canadian contributions





"VUV-sensitive silicon photomultipliers for xenon scintillation light detection in nEXO", *IEEE Transactions on Nuclear Science* (2018) 65, 11, 2823



"Study of silicon photomultiplier performance in external electric fields", *JINST* (2018) 13, 09, T09006



"Reflectance of silicon photomultipliers at vacuum ultraviolet wavelengths", arXiv:1912.01841



"Reflectivity and PDE of VUV4 Hamamatsu SiPMs in liquid xenon", *JINST* (2020) 15, 01, P01019 12



- Vacuum ultra-violet efficiency, reflectivity and absorption (VERA) test setup at TRIUMF
  - Measuring reflectivity and efficiency at the same time
  - New improvements to temperature control  $\rightarrow$  stability better than 0.1 K





- Measurements at TRIUMF generally show satisfactory performance from FBK and Hamamatsu devices at LXe temperature (165 K)
  - Correlated avalanches: Hamamatsu device can be operated at higher overvoltage compared to FBK
  - Dark noise rate requirement easily satisfied



"Characterization of the Hamamatsu VUV4 MPPCs for nEXO", NIM A (2019) C940, 6



- Measurements at TRIUMF generally show satisfactory performance from FBK and Hamamatsu devices at LXe temperature (165 K)
  - Photon detection efficiency: FBK meets specification, Hamamatsu comes close



"Characterization of the Hamamatsu VUV4 MPPCs for nEXO", NIM A (2019) C940, 6

#### Photodetector system options

**Analog** SiPM tiles, with front-end circuits and ADC on readout ASIC



Photon to **Digital** Converter (PDC) arrays with tile controller ASIC

### Photon to Digital Converters



- Prototype PDC achieved at U. de Sherbrooke:
  - Analog front-end circuit replaced by **digital quenching readout** 
    - Digitize signals from each photodiode in situ
    - Reduced power dissipation
    - Noise reduction owing to enhanced capabilities and flexibility of *configurable digital readout electronics*
- **3D integration**, maximizing sensitive area

Photon to digital converter tile concept



#### Photon to Digital Converters

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 PDC CMOS readout chip is now fully operational (U. de Sherbrooke)





### Photon to Digital Converters

#### • Next R&D objectives for PDC:

#### • VUV-sensitivity

- Strategy 1: Delta doping in collaboration with LBNL
- Strategy 2: Teledyne e2v backside-illuminated tech.

#### • Silicon interposer

- Match coefficient of thermal expansion of PDC with its electrical/mechanical substrate
- Low radioactivity
- Low contaminant for LXe
- Collaboration with IZM Fraunhofer (Berlin)
- Establish yield vs. size
- "Long" transmission lines with low resistivity and low capacitance (analog and digital signals)



#### Light-only Liquid Xenon (LoLX)





- Canadian collaboration (mostly)
- Phase 1 objectives
  - Gain experience operating many SiPM channels: first in vacuum, then in LXe
  - Measure scintillation and Cherenkov light yields
    - Using <sup>90</sup>Sr and <sup>210</sup>Po sources
  - Ex-situ optical measurements to verify GEANT4 optical simulations
  - Assess external cross-talk (light emission by SiPMs)
- Status: Currently running at McGill

#### Further SiPM tests in LXe

- Existing LXe cryostat: EXO-100
  - Current inner detector used for nEXO HV tests
- Planning future SiPM tests with LoLX-HV:
  - Ensure functionality of tiles in nEXO's harshest possible environment
    - High electric field with possible charge-up
    - **High rate** when calibrating with sources
  - Operation of tiles in LXe
  - Detection of surface alphas
    - Very bright localized light flashes





#### **EXO-100 cryostat**

currently being recommissioned at Carleton U.

Yellow: Inner chamber for detector in LXe Blue: Liquid nitrogen tank with exhaust lines Red: Outer insulation vacuum vessel

#### Large-scale integration and testing

#### Getting ready for nEXO construction

- TRIUMF proposed as main SiPM wafer testing and dicing site, and backup tile production facility (BNL primary)
- McGill developing and prototyping procedure for SiPM stave testing and assembly in nEXO underground
  - Very fragile staves must be handled with great care!
- **Quality control**: Ensure that staves will survive 10 years of operation in nEXO
  - Long term stability, Temperature cycle, Vibrations
- **Functionality tests** with environmental chamber:
  - Movable mirrors guide photons to SiPM stave under test
  - Electroluminescent source of VUV photons under development at McGill



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#### Design of full-length stave test chamber <sub>22</sub>

#### Large-scale integration and testing

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Test setup in action at McGill

### Summary and Outlook



- Light detection using VUV-sensitive SiPM is critical for nEXO
  - Excellent energy resolution  $\rightarrow$  Sensitivity to  $0\nu\beta\beta$
- Canadian contributions to photodetector R&D
  - Characterize SiPM performance to make sure that nEXO photodetector requirements are satisfied
  - Test SiPM single devices and tiles optically, and in LXe
  - Complete development of VUV-sensitive Photon to Digital Converters and silicon interposer technology
- Getting ready for nEXO construction

#### Thank you! Merci!



#### nEXO Collaboration, June 2019



















#### **Bonus slides**

### Energy resolution in nEXO

- Neutrinoless double beta decay discovery requires the best possible energy resolution
  - Relies on the combination of charge and light collection in the single-phase LXe TPC
  - Cancels fluctuations in ionization vs. scintillation yield





### Ovββ experiments sensitivity

- nEX®
- At  $\langle m_{\beta\beta} \rangle \sim 0.01$  eV, nEXO projected sensitivity compares favourably with current and proposed 0v $\beta\beta$  experiments



Agostini, Benato, Detwiler, PRD 96 (2017) 053001; and A. Caldwell et al., PRD 96 (2017) 073001